

TOSHIBA Field Effect Transistor Silicon P Channel MOS Type

SSM6J06FU

Power Management Switch
High Speed Switching Applications

- Small package
- Low on resistance: Ron = 0.5 Ω max (VGS = -4 V)
: Ron = 0.7 Ω max (VGS = -2.5 V)
- Low gate threshold voltage

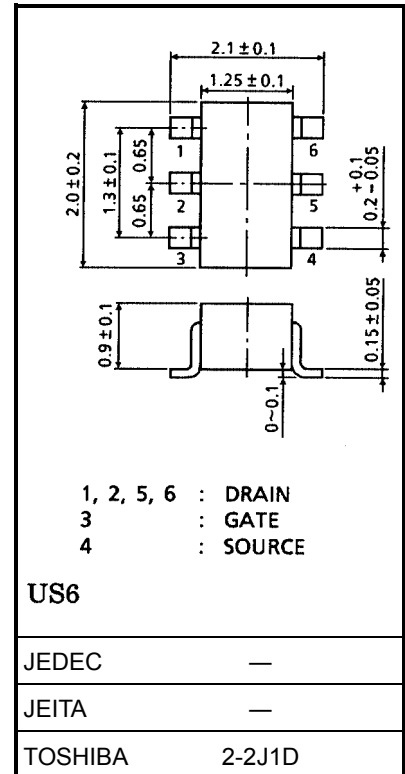
Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Rating	Unit
Drain-source voltage	V _{DS}	-20	V
Gate-source voltage	V _{GSS}	±12	V
Drain current	DC	I _D	-650
	Pulse	I _{DP}	-1300
Drain power dissipation (Ta = 25°C)	P _D (Note 1)	300	mW
Channel temperature	T _{ch}	150	°C
Storage temperature range	T _{stg}	-55~150	°C

Note 1: Mounted on FR4 board.

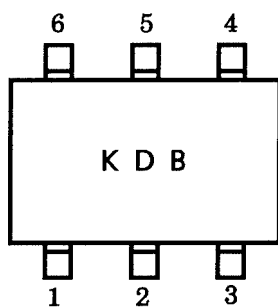
(25.4 mm × 25.4 mm × 1.6 t, Cu pad: 0.32 mm² × 6) Figure 1.

Unit: mm

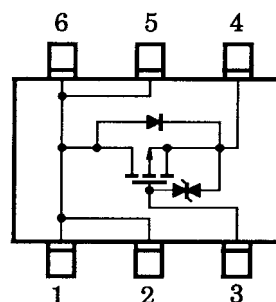


Weight: 6.8 mg (typ.)

Marking



Equivalent Circuit



Handling Precaution

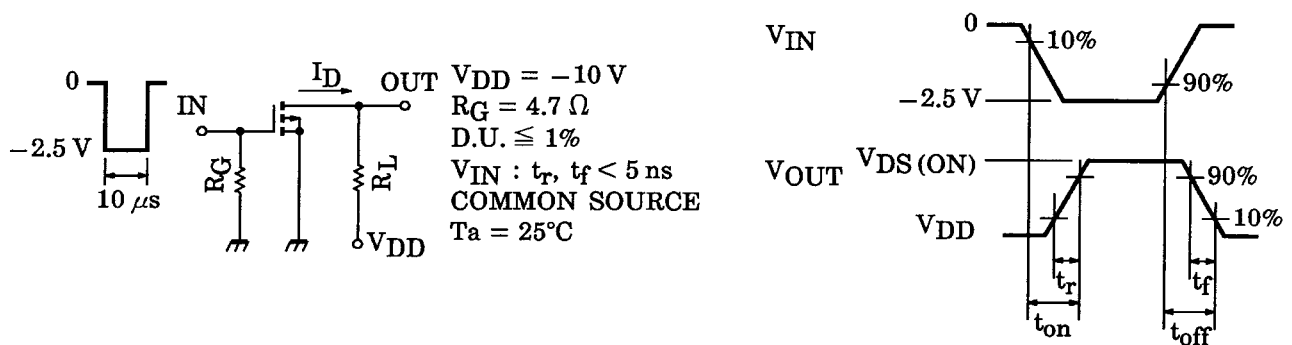
When handling individual devices (which are not yet mounting on a circuit board), be sure that the environment is protected against electrostatic electricity. Operators should wear anti-static clothing, and containers and other objects that come into direct contact with devices should be made of anti-static materials.

Electrical Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Gate leakage current	I_{GSS}	$V_{GS} = \pm 12\text{ V}, V_{DS} = 0$	—	—	± 1	μA
Drain-source breakdown voltage	$V_{(BR)DSS}$	$I_D = -1\text{ mA}, V_{GS} = 0$	-20	—	—	V
Drain cut-off current	I_{DSS}	$V_{DS} = -20\text{ V}, V_{GS} = 0$	—	—	-1	μA
Gate threshold voltage	V_{th}	$V_{DS} = -3\text{ V}, I_D = -0.1\text{ mA}$	-0.6	—	-1.1	V
Forward transfer admittance	$ Y_{fs} $	$V_{DS} = -3\text{ V}, I_D = -0.3\text{ A}$ (Note 2)	0.6	—	—	S
Drain-source ON resistance	$R_{DS(ON)}$	$I_D = -0.3\text{ A}, V_{GS} = -4\text{ V}$ (Note 2)	—	0.4	0.5	Ω
		$I_D = -0.3\text{ A}, V_{GS} = -2.5\text{ V}$ (Note 2)	—	0.55	0.7	
Input capacitance	C_{iss}	$V_{DS} = -10\text{ V}, V_{GS} = 0, f = 1\text{ MHz}$	—	160	—	pF
Reverse transfer capacitance	C_{rss}	$V_{DS} = -10\text{ V}, V_{GS} = 0, f = 1\text{ MHz}$	—	25	—	pF
Output capacitance	C_{oss}	$V_{DS} = -10\text{ V}, V_{GS} = 0, f = 1\text{ MHz}$	—	90	—	pF
Switching time	Turn-on time	$V_{DD} = -10\text{ V}, I_D = -0.3\text{ A},$ $V_{GS} = 0 \sim -2.5\text{ V}, R_G = 4.7\ \Omega$	—	27	—	ns
	Turn-off time		—	43	—	

Note 2: Pulse test

Switching Time Test Circuit



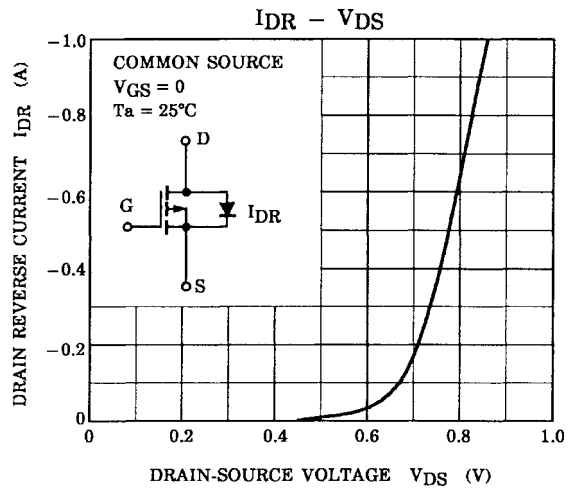
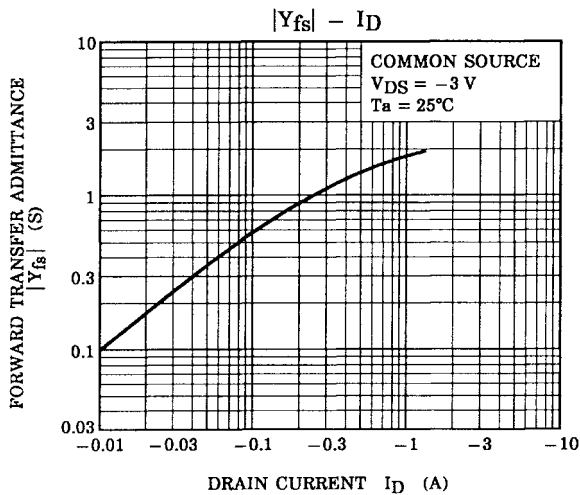
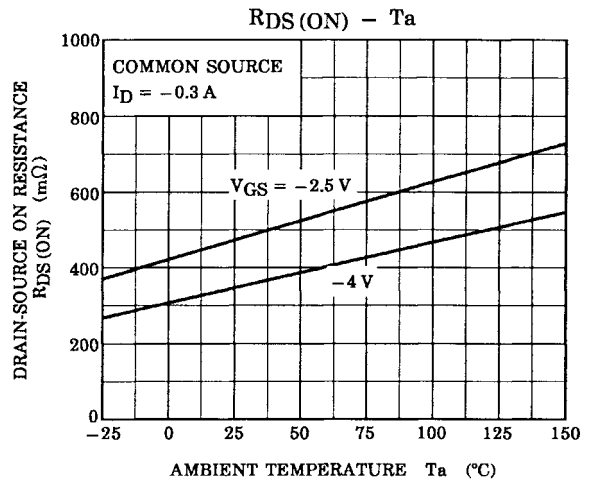
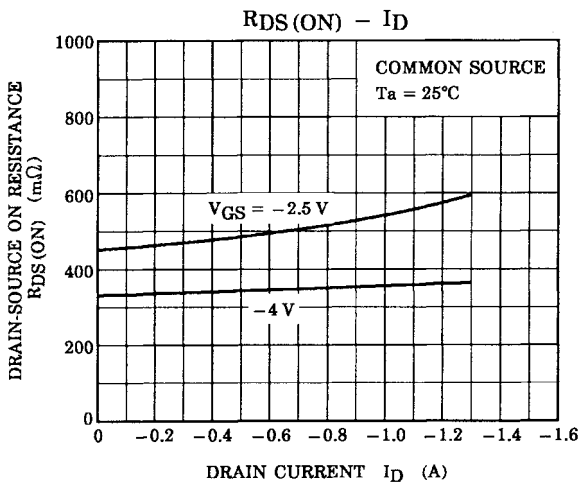
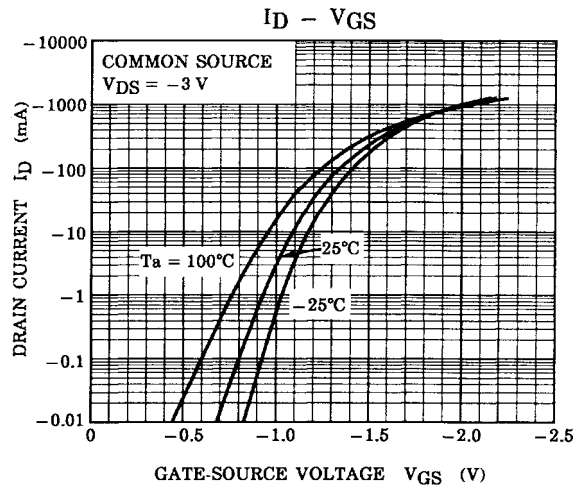
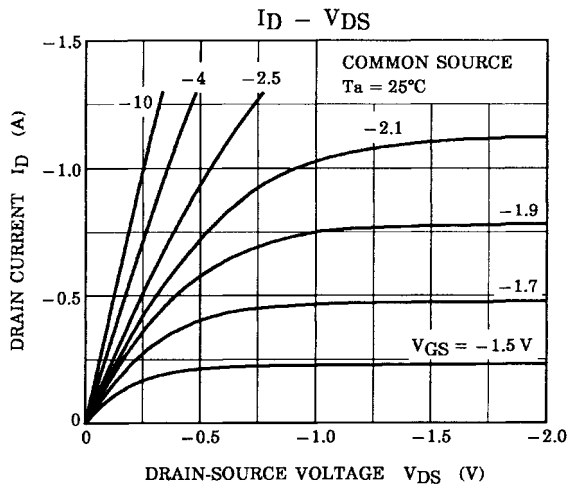
Precaution

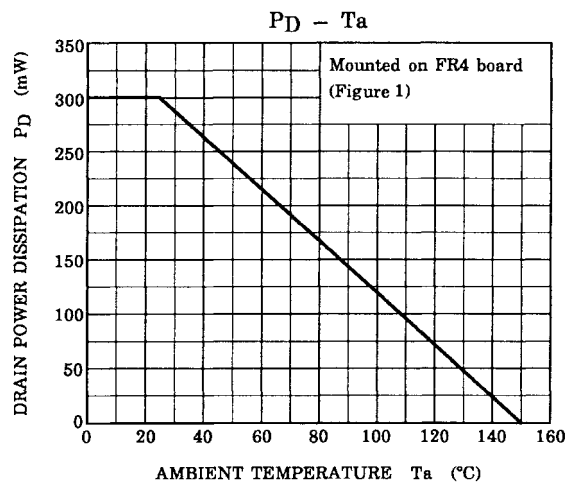
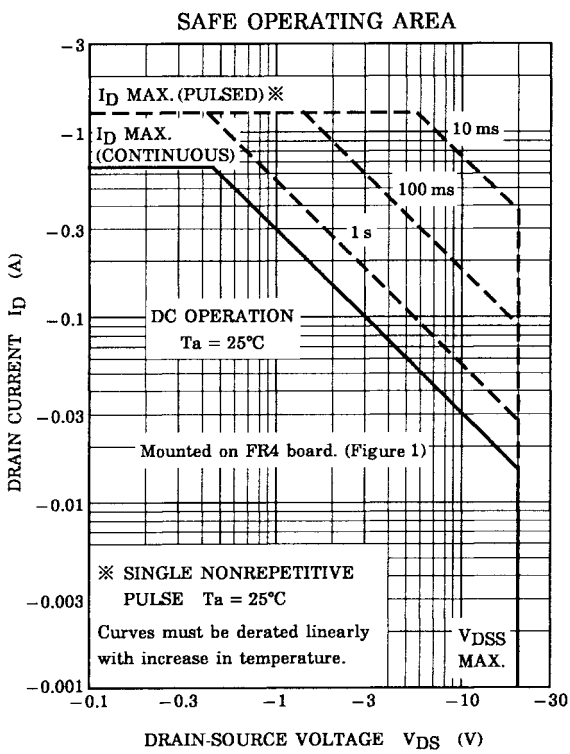
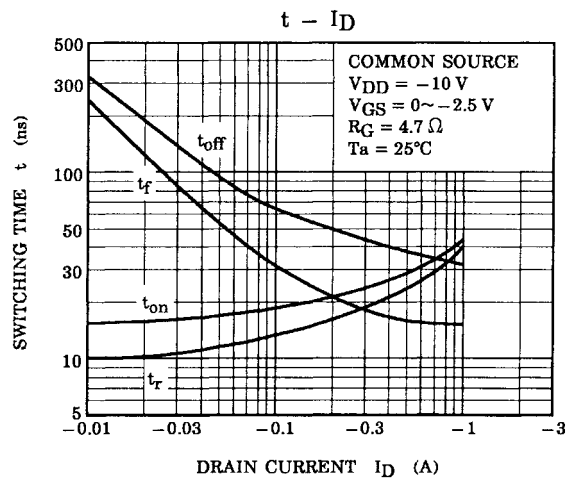
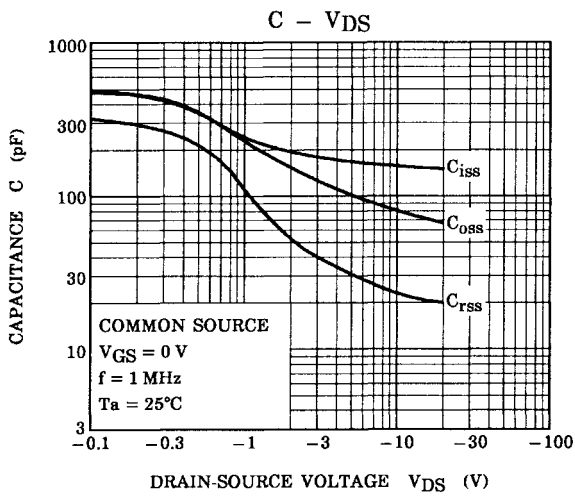
V_{th} can be expressed as voltage between gate and source when low operating current value is $I_D = -100\ \mu\text{A}$ for this product. For normal switching operation, $V_{GS(ON)}$ requires higher voltage than V_{th} and $V_{GS(OFF)}$ requires lower voltage than V_{th} .

(Relationship can be established as follows: $V_{GS(OFF)} < V_{th} < V_{GS(ON)}$)

Please take this into consideration for using the device.

V_{GS} recommended voltage of -2.5 V or higher to turn on this product.





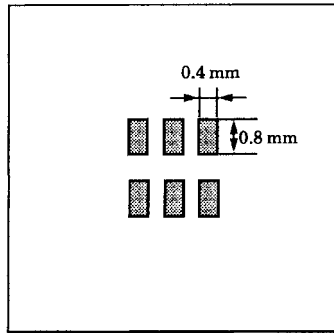


Figure 1 25.4 mm × 25.4 mm × 1.6 t, Cu Pad: 0.32 mm² × 6

RESTRICTIONS ON PRODUCT USE

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